### **Vishay Semiconductors**

Hyperfast Rectifier, 16 A FRED Pt<sup>®</sup>



www.vishay.com

Cathode O Anode 2

PRODUCT SUMMARY					
Package	TO-263AC (SMPD)				
I <sub>F(AV)</sub>	16 A				
V <sub>R</sub>	200 V				
V <sub>F</sub> at I <sub>F</sub>	0.75 V				
t <sub>rr</sub>	32 ns				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				

#### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		200	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>solder pad</sub> = 152 °C	16	٨			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 6 ms square pulse	250	A			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-		
En averal vielde en	V <sub>F</sub>	I <sub>F</sub> = 16 A	-	0.91	1.0	V	
Forward voltage		I <sub>F</sub> = 16 A, T <sub>J</sub> = 150 °C	-	0.75	0.84		
	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	15		
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	60	-	pF	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \ dI_F/dt = 50 \text{ A}$	Vµs, V <sub>R</sub> = 30 V	-	32	-	
Reverse recovery time	+	$I_{\rm F} = 0.5 \; {\rm A}, \; I_{\rm R} = 1 \; {\rm A}, \; I_{\rm rr}$	-	-	32		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-	ns
		T <sub>J</sub> = 125 °C		-	40	-	
Deels receiver a surrent		T <sub>J</sub> = 25 °C	$I_{\rm F} = 16  {\rm A},$	-	2.8	-	^
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs, V <sub>R</sub> = 160 V	-	6	-	A
	0	T <sub>J</sub> = 25 °C		-	37	-	
Reverse recovery charge Q <sub>rr</sub>		T <sub>J</sub> = 125 °C		-	125	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C	
Thermal resistance, junction to solder pad	R <sub>thJ-Sp</sub>		-	1.1	1.5	°C/W	
Approximate weight				0.55		g	
				0.02		oz.	
Marking device		Case style TO-263AC (SMPD)		16EI	DH02		

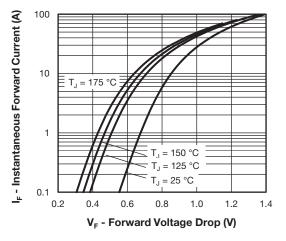


Fig. 1 - Typical Forward Voltage Drop Characteristics

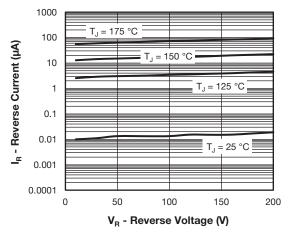


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

### VS-16EDH02-M3

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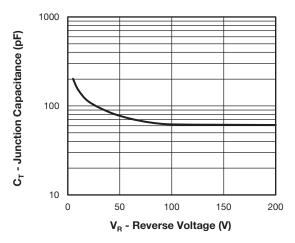


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

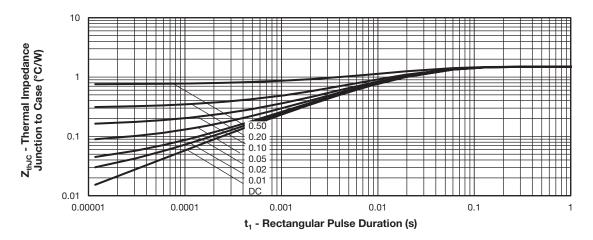
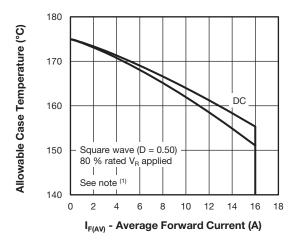
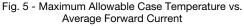


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{R(AV)} \times V_{FM} \mbox{at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 5);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{rated} \mbox{V}_{R1} \\ \end{array}$ 

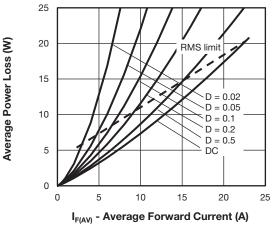


Fig. 6 - Forward Power Loss Characteristics

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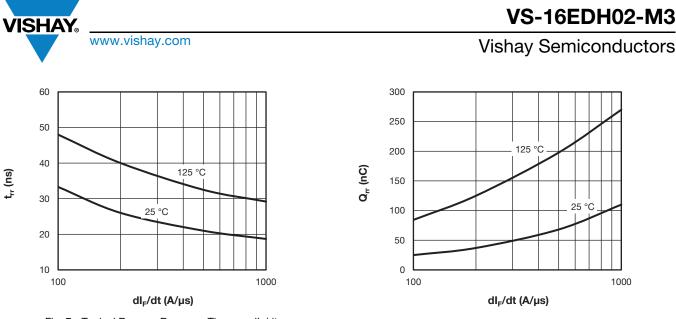


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



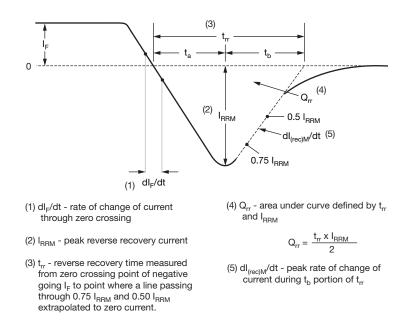


Fig. 9 - Reverse Recovery Waveform and Definitions





#### **ORDERING INFORMATION TABLE**

Device code	VS-	16	Е	D	н	02	-M3
	1	2	3	4	5	6	7
	1	- Visl	nay Sen	nicondu	ctors pr	oduct	
	2	- Cur	rent rati	ng (16 A	A)		
	3	- Circ	cuit cont	figuratio	n:		
		E =	single c	lie			
	4	- D=	SMPD	package	Э		
	5	- Pro	cess typ	be,			
		H =	hyperfa	ast recov	/ery		
	6	- Vol	tage coo	de (02 =	200 V)		
	7	M3	3 = halog	gen-free	e, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-16EDH02-M3/I	2000	2000	13" diameter plastic tape and reel				

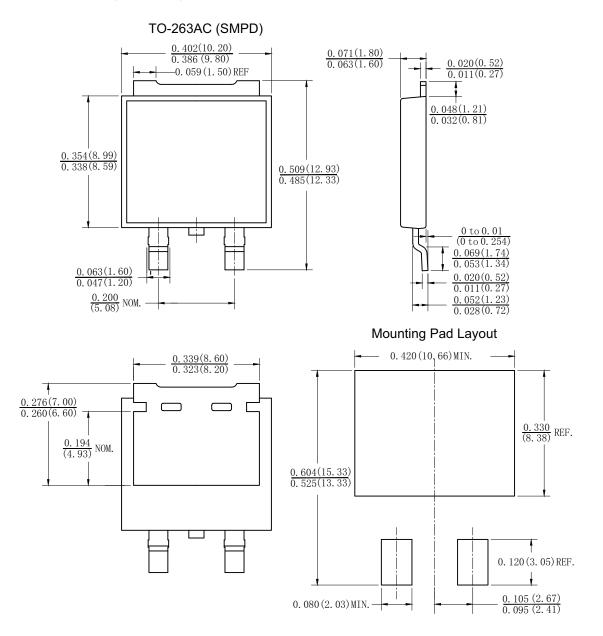
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				





TO-263AC (SMPD)

#### **DIMENSIONS** in inches (millimeters)





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